

6427525 N E C ELECTRONICS INC

05E 22688 D

BIPOLAR ANALOG INTEGRATED CIRCUIT

μ PC1213C

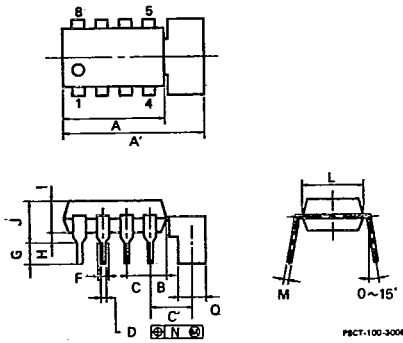
T-74-05-01

AUDIO POWER AMPLIFIER

DESCRIPTION

The μ PC1213C is a silicon monolithic integrated circuit designed for an audio power amplifier used in a portable radio receiver or a portable cassette tape recorder which works at 9-volt power supply. The μ PC1213C is encapsulated in an 8-pin dual in-line plastic package with a tab.

8 PIN PLASTIC DIP WITH TAB (300 mil)



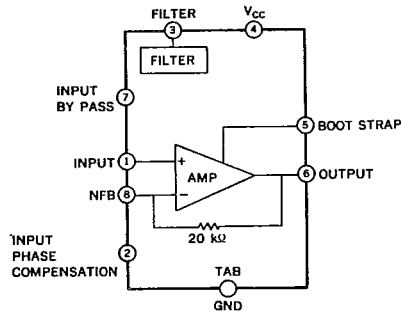
| ITEM | MILLIMETERS | INCHES |
|------|-----------------|-------------------|
| A | 12.70 MAX. | 0.500 MAX. |
| A' | 14.80 MAX. | 0.571 MAX. |
| B | 2.54 MAX. | 0.100 MAX. |
| C | 2.54 (T.P.) | 0.100 (T.P.) |
| C' | 3.85 | 0.144 |
| D | 0.50 \pm 0.10 | 0.020 \pm 0.004 |
| F | 1.1 MIN. | 0.043 MIN. |
| G | 3.5 \pm 0.3 | 0.138 \pm 0.012 |
| H | 0.51 MIN. | 0.020 MIN. |
| I | 4.31 MAX. | 0.170 MAX. |
| J | 5.08 MAX. | 0.200 MAX. |
| L | 6.4 | 0.252 |
| M | 0.30 \pm 0.04 | 0.012 \pm 0.002 |
| N | 0.25 | 0.01 |
| Q | 2.62 \pm 0.10 | 0.103 \pm 0.004 |

NOTE
1) Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.

FEATURES

- High output power.
 $P_o = 2.4$ W (TYP.)
at $V_{CC} = 9$ V, $R_L = 4 \Omega$, T.H.D. = 10 %
- Wide operating voltage range.
 $V_{CC} = 4.5$ to 9 to 11 V
- High ripple rejection ratio.
R.R.R. = 55 dB (TYP.)
- Soft clipping waveform.
- Have a muting circuit so that no shock noise at power supply switch on and off.
- Have a terminal to reject interference noise in strong electric field. (pin 2)

BLOCK DIAGRAM



CONNECTION DIAGRAM

| No. | CONNECTION | No. | CONNECTION |
|-----|------------|-----|------------|
| 1 | INPUT | 5 | BOOTSTRAP |
| 2 | | 6 | OUTPUT |
| 3 | FILTER | 7 | FILTER |
| 4 | V_{CC} | 8 | N. F. B. |
| TAB | GND | | |

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ABSOLUTE MAXIMUM RATINGS (T_a = 25 °C)

| | | | | |
|-----------------------------|------------------|-------------|------------|----|
| Supply Voltage | V _{CC1} | (No Signal) | 16 | V |
| Supply Voltage | V _{CC2} | (Operating) | 11 | V |
| Allowable Power Dissipation | P _d | * | 2.4 | W |
| Operating Temperature | T _{opt} | | -20 to 70 | °C |
| Storage Temperature | T _{stg} | | -40 to 150 | °C |

* 50 x 50 x 0.035 mm³ copper heat sink on P.C.B.

RECOMMENDED CONDITIONS (T_a = 25 °C)

| | |
|----------------|------------------------------------|
| Supply Voltage | V _{CC} = 4.5 to 9 to 11 V |
| Load Impedance | R _L = 4 Ω |

ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

(V_{CC} = 9 V, R = 4Ω, f = 1 kHz, Refer to the test circuit
50 x 50 x 0.035 mm³ copper heat sink on P.C.B. unless otherwise specified)

| CHARACTERISTIC | SYMBOL | MIN. | TYP. | MAX. | UNIT | CONDITION |
|--------------------------------|---------------------|------|------|------|----------------------|---|
| Quiescent Circuit Current | I _{CC} | 8 | 15 | 25 | mA | No Signal |
| Open Loop Voltage Gain | A _{vo} | 55 | 65 | | dB | P _O = 0.25 W |
| Voltage Gain (Closed Loop) | A _v | 41 | 45 | 48 | dB | R _f = 100 Ω |
| | | | 34 | | | R _f = 360 Ω |
| Output Power | P _O | 1.8 | 3.6 | | W | T.H.D. = 10 % |
| | | | 2.2 | | | R _f = 100 Ω |
| | | | 2.4 | | | V _{CC} = 11 V, R _L = 4 Ω |
| | | | 1.3 | | | V _{CC} = 11 V, R _L = 8 Ω |
| | | | 1.0 | | | V _{CC} = 9 V, R _L = 4 Ω |
| | | | 0.54 | | | V _{CC} = 9 V, R _L = 8 Ω |
| Input Sensitivity | V _{i(rms)} | | 19.5 | | mV | P _O = 2.4 W |
| | | | 47.3 | | | R _L = 4 Ω |
| | | | | | | R _f = 100 Ω (A _v = 45 dB) |
| Input Sensitivity | V _{i(rms)} | | 2.5 | | mV | P _O = 50 mW |
| | | | 8.9 | | | R _L = 4 Ω |
| | | | | | | R _f = 100 Ω (A _v = 45 dB) |
| Total Harmonic Distortion | T.H.D. | | 0.4 | 1.5 | % | P _O = 0.25 W |
| Output Noise Voltage | NL | | 0.2 | 0.8 | mV _{r.m.s.} | R _G = 0 |
| Supply Voltage Rejection Ratio | S.V.R. | 40 | 55 | | dB | R _G = 0, f _{ripple} = 100 Hz V _{ripple} = 0.3 V _{r.m.s.} |
| Input Impedance | R _i | 10 | 20 | | kΩ | |

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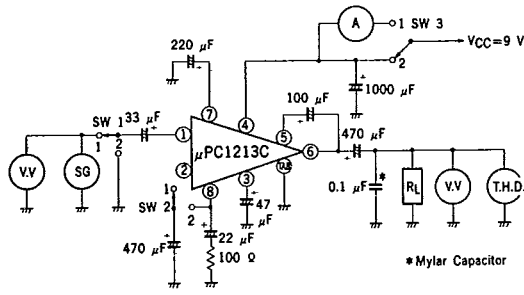
NOTE: In case that only a TYP. value is specified, this specification is for helping to design.

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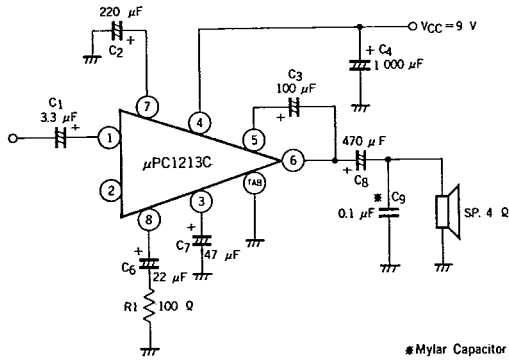
TEST CIRCUIT
Fig. 1 TEST CIRCUIT



SWITCH POSITION

| | | SWITCH | | |
|---------------------------|----------|--------|-----|-----|
| ITEM | | SW1 | SW2 | SW3 |
| Circuit Current | I_{CC} | 2 | 1 | 1 |
| Open Loop Voltage Gain | A_{VO} | 1 | 2 | 2 |
| Voltage Gain | A_V | 1 | 1 | 2 |
| Output Power | P_O | 1 | 1 | 2 |
| Total Harmonic Distortion | T.H.D. | 1 | 1 | 2 |
| Output Noise Voltage | NL | 2 | 1 | 2 |

TYPICAL APPLICATION
Fig. 2 SINGLE OPERATION



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Fig. 3 BTL OPERATION

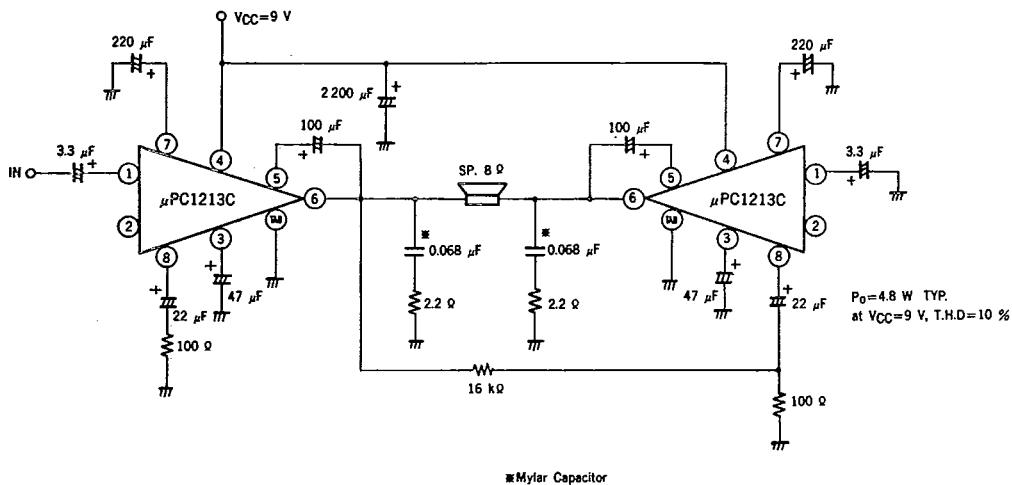
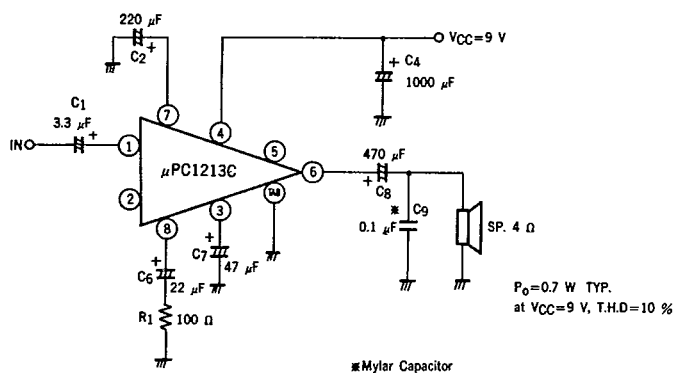


Fig. 4 SINGLE OPERATION WITHOUT BOOTSTRAP



NOTE FOR USE

- (1) Capacitor C_9 is for preventing the parasitic oscillation. A mylar capacitor is recommended for this position.
- (2) The ground side of C_4 , C_9 and the loud speaker should be attached at the place of the copper foil close to the tab of μ PC1212C.
- (3) Interference noise rejection in a strong electric field can be achieved by adding a capacitor (about 1 000 pF) between pin 1 and pin 2.

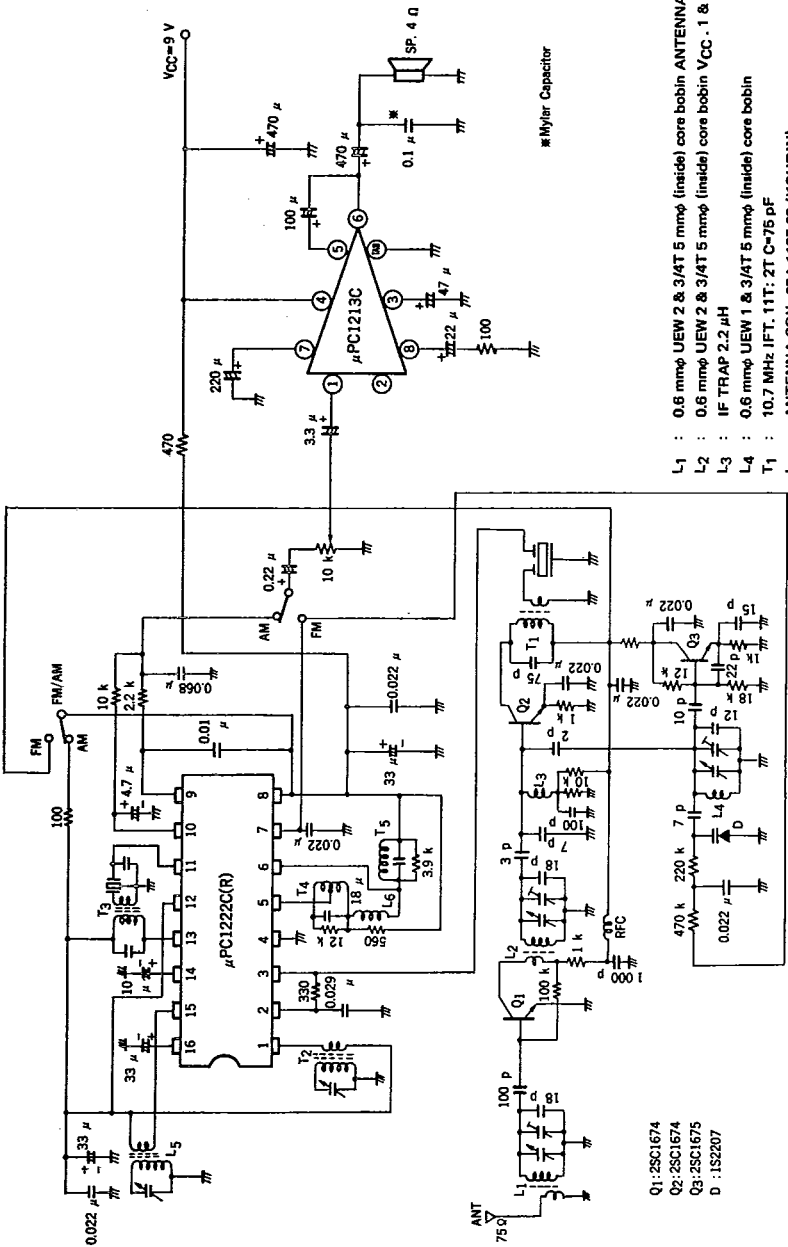
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- L1 : 0.6 mmφ UEW 2 & 3/AT 5 mmφ (inside) core bobbin ANTENNA 3/4T
- L2 : 0.6 mmφ UEW 2 & 3/AT 5 mmφ (inside) core bobbin VCC .1 & 3/4T
- L3 : IF TRAP 2.2 µH
- L4 : 0.6 mmφ UEW 1 & 3/AT 5 mmφ (inside) core bobbin
- T1 : 10.7 MHz IFT, 11T, 2T C-75 pF
- L5 : ANTENNA COIL, 25A-1195-08 (KOHRIN)
- T2 : AM OSC 26-1791-13 (KOHRIN)
- T3 : AM IFT CFZ-455C (TOKO)
- T4 : AM DET. 5251 (TOKO)
- T5 : FM DET. 12747 (TOKO)
- L6 : PHASE SHIFT COIL 7BA180JH (TOKO)

*Mylar Capacitor

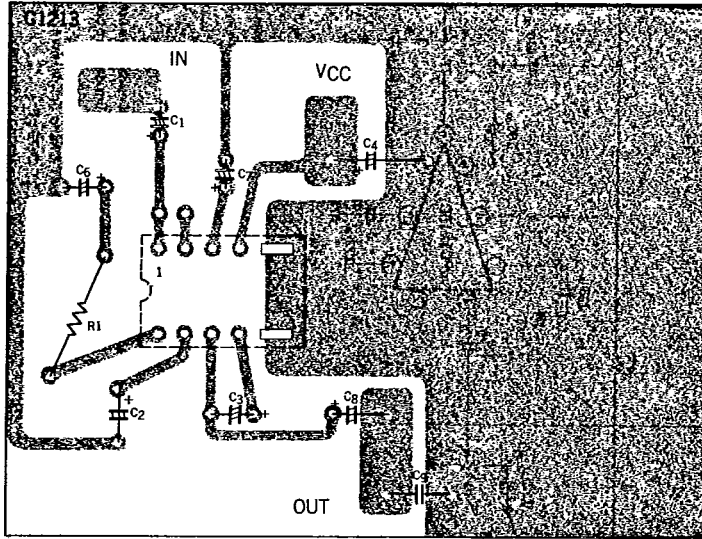
APPLICATION INFORMATION
Fig. 5 LOW COST FM-AM RADIO WITH 2.4 W OUTPUT POWER (V_{CC} = 9 V)

Q1: 2SC1674
Q2: 2SC1674
Q3: 2SC1675
D : 1S2207

UNIT : Capacitance F
Resistance Ω

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P.C. BOARD PATTERN (COPPER SIDE)

μ PC1213C
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μ PC1213C

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TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

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Fig. 6 OUTPUT POWER vs. SUPPLY VOLTAGE

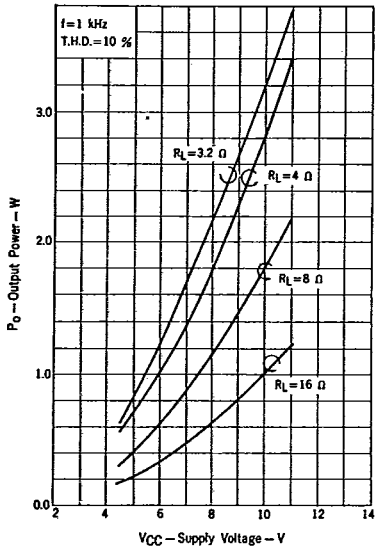


Fig. 7 TOTAL HARMONIC DISTORTION vs. OUTPUT POWER

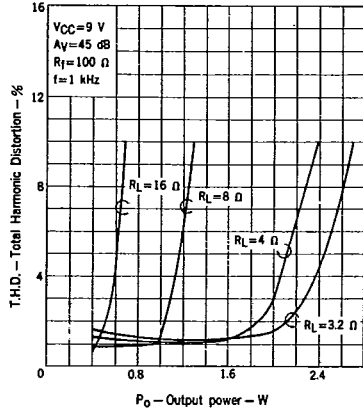
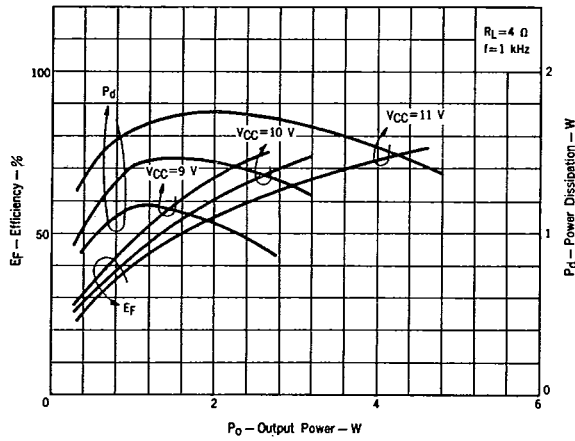


Fig. 8 POWER DISSIPATION AND EFFICIENCY vs. OUTPUT POWER



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Fig. 10 QUIESCENT OUTPUT VOLTAGE AT PIN 6 vs. SUPPLY VOLTAGE

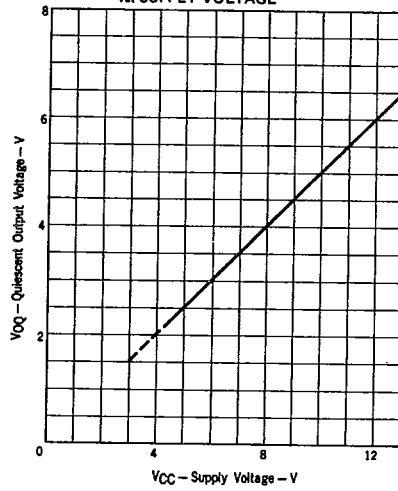


Fig. 9 VOLTAGE GAIN (CLOSED LOOP) vs. R_f

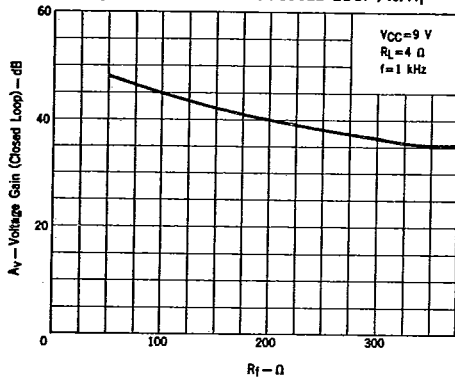


Fig. 11 INPUT SENSITIVITY vs. R_f

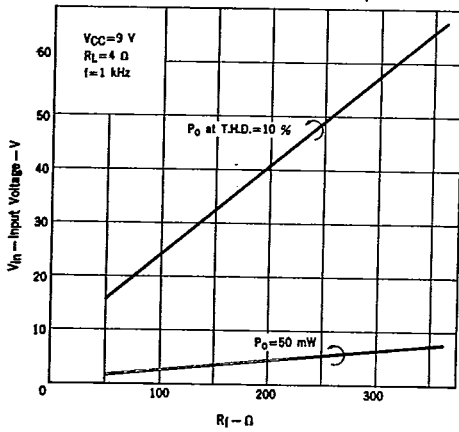
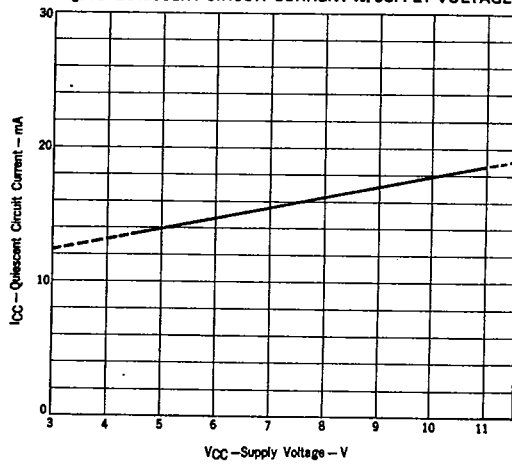


Fig. 12 QUIESCENT CIRCUIT CURRENT vs. SUPPLY VOLTAGE



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Fig. 13 OPEN LOOP VOLTAGE GAIN, VOLTAGE GAIN vs. FREQUENCY

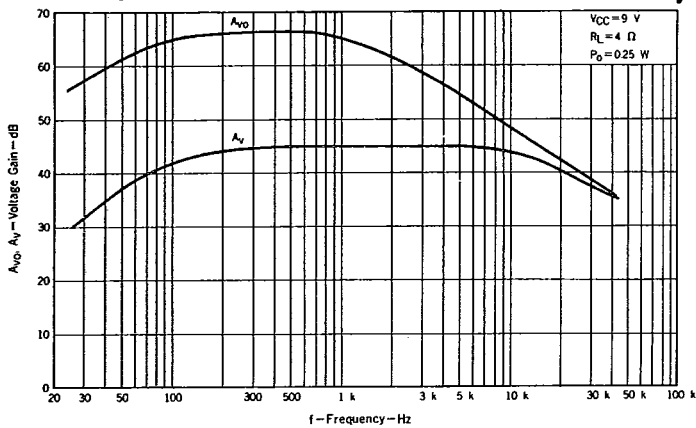


Fig. 14 TOTAL HARMONIC DISTORTION vs. FREQUENCY

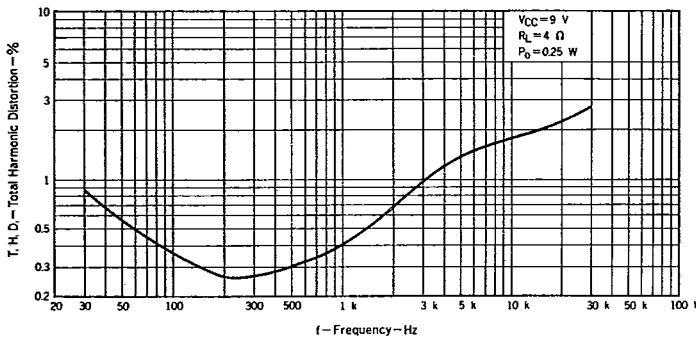
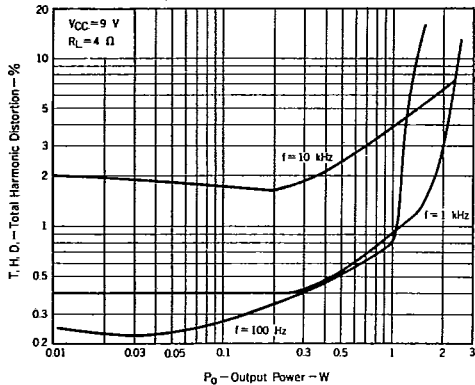
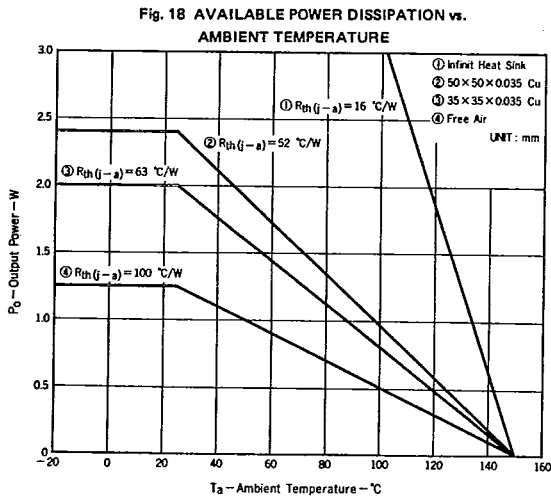
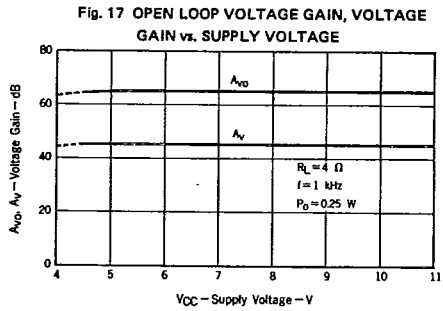
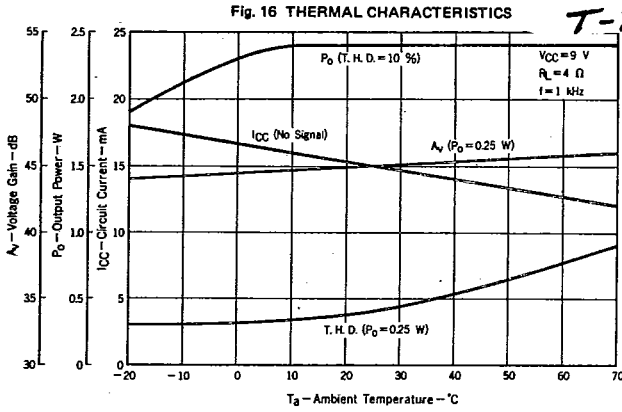


Fig. 15 TOTAL HARMONIC DISTORTION vs. OUTPUT POWER



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DESIGN OF HEAT SINK

Keep much margin at the design of heat sink.

The heat sink shown the folling sentence is nessesary when the μ PC1213C is operated under next conditions.

Conditions : Maximum Operating Voltage 10 V
 Maximum Ambient Temperature 70 °C
 Load Impedance 4 Ω

There is the equation between junction temperature and thermal resistance.

$$T_j = T_a + R_{th(j-a)} \times P_d \quad (1)$$

T_j : Junction Temperature

T_a : Ambient Temperature

$R_{th(j-a)}$: Thermal Resistance (Junction to Ambient)

P_d : Power Dissipation

According to Fig. 8, $P_d(\text{MAX.}) = 1.42 \text{ W}$ at $V_{CC} = 10 \text{ V}$

And absolute maximum rating shows, $T_j < 150 \text{ }^\circ\text{C}$

From the equation (1) and those values,

$$R_{th(j-a)} < 56.3 \text{ }^\circ\text{C/W} \quad (2)$$

According to Fig. 18, copper size on P.C.B. satisfying the inequality (2) is $50 \times 50 \times 0.035 \text{ mm}^3$.